imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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EMH2408

N-Channel Power MOSFET 20V, 4A, 45m Ω , Dual EMH8



Features

- The EMH2408 incorporates a N-channel MOSFET that feature low ON-resistance and ultrahigh-speed switching, thereby enabling high-density mounting
- 1.8V drive
- Halogen free compliance

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		20	V
Gate-to-Source Voltage	VGSS		±12	V
Drain Current (DC)	ID		4	А
Drain Current (Pulse)	IDP	PW≤10µs, duty cycle≤1%	16	А
Allowable Power Dissipation	PD	When mounted on ceramic substrate (900mm ² ×0.8mm) 1unit	1.0	W
Total Dissipation	PT	When mounted on ceramic substrate (900mm ² ×0.8mm)	1.2	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

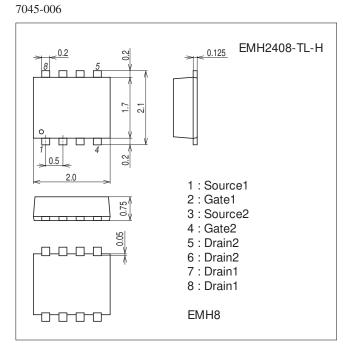
This product is designed to "ESD immunity < 200V*", so please take care when handling.

* Machine Model

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions





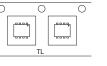
Product & Package Information

- Package : EMH8
- JEITA, JEDEC
- Minimum Packing Quantity : 3,000 pcs./reel

Packing Type : TL

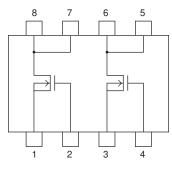
Marking

: -



LH o Lot No.

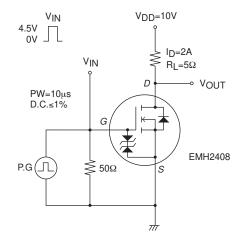
Electrical Connection



Electrical Characteristics at Ta=25°C

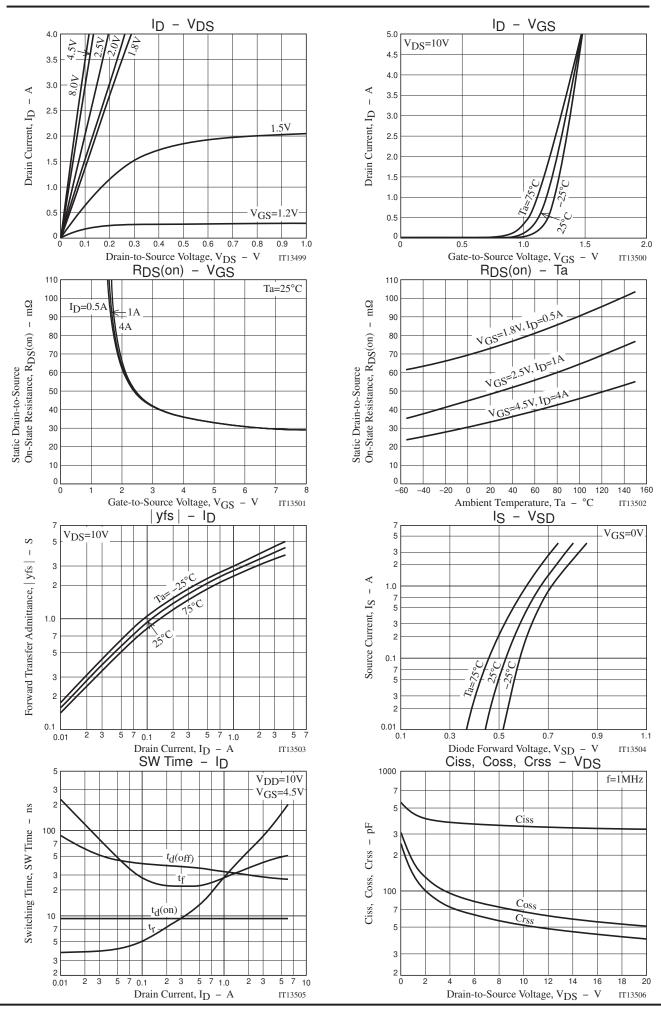
Devemeter	Cumbal		Ratings			1.114	
Parameter	Symbol	Conditions	min	typ	max	Unit	
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	20			V	
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =20V, V _{GS} =0V			1	μA	
Gate-to-Source Leakage Current	IGSS	V _{GS} =±8V, V _{DS} =0V			±10	μA	
Cutoff Voltage	V _{GS} (off)	V _{DS} =10V, I _D =1mA	0.4		1.3	V	
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =2A	2.0	3.4		S	
Static Drain-to-Source On-State Resistance	R _{DS} (on)1	ID=4A, VGS=4.5V		34	45	mΩ	
	R _{DS} (on)2	ID=1A, VGS=2.5V		49	67	mΩ	
	R _{DS} (on)3	ID=0.5A, VGS=1.8V		74	115	mΩ	
Input Capacitance	Ciss			345		pF	
Output Capacitance	Coss	V _{DS} =10V, f=1MHz		67		pF	
Reverse Transfer Capacitance	Crss			52		pF	
Turn-ON Delay Time	t _d (on)			9.2		ns	
Rise Time	tr			60		ns	
Turn-OFF Delay Time	td(off)	See specified Test Circuit.		30		ns	
Fall Time	tf			38		ns	
Total Gate Charge	Qg			4.7		nC	
Gate-to-Source Charge	Qgs	V _{DS} =10V, V _{GS} =4.5V, I _D =4A		0.65		nC	
Gate-to-Drain "Miller" Charge	Qgd	1		1.6		nC	
Diode Forward Voltage	VSD	I _S =4A, V _{GS} =0V		0.8	1.2	V	

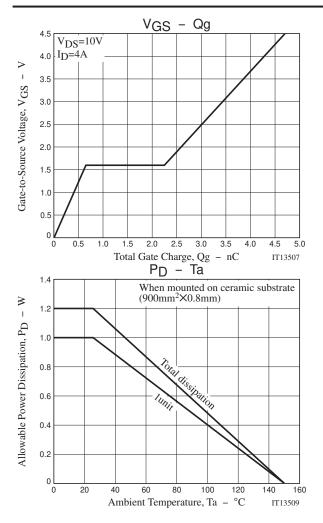
Switching Time Test Circuit

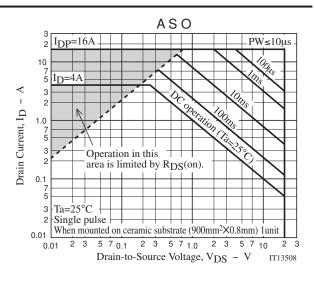


Ordering Information

Device Package		Shipping	memo
EMH2408-TL-H	EMH8	3,000pcs./reel	Pb Free and Halogen Free







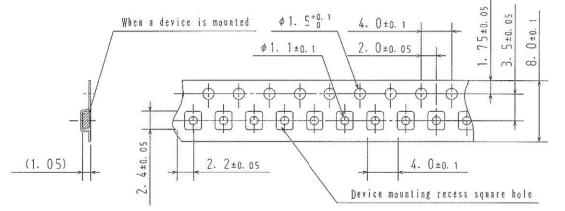
Embossed Taping Specification EMH2408-TL-H

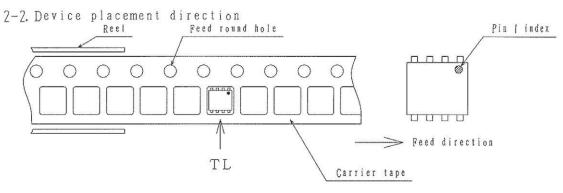
1. Packing Format

Package Name			ximum Number of ces contained (pcs)		Packing format		
	Туре	Reel	Inner box	Quter box	Inner BOX (C-1) Outer BOX (A-7)		
EMH8	MCP4	3,000	15,000	90,000	5 reels contained 6 inner boxes contained		
					Dinensions:mm (external) Dimensions:mm (external)		
					183×72×185 440×195×210		
Reel label, [nner box labelQuter box label							
Packing method (unit:mm) It is a label at the time of factory shipments. The form of a label may change in physical distribution process.							
•			k		59 108		
	Type LOT Quan Orig	No. tity		7 LOT 00 1 11 11 11 11 11 11 11 11 GTY 0,00 1 51 11 11 11 11 11 SPECTAL 11 11 11 11 11 11 11 11 * 2 0 7 2 2 1	Imilian <t< td=""></t<>		
NOTE (1) <u>Reel label</u> treatment of the terminal i				REE & description shows that the surface			
				Label	JEITA Phase		
				LEAD FRI			

2. Taping configuration

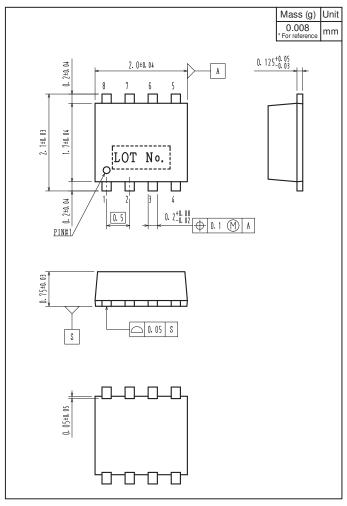
2-1. Carrier tape size (unit:mm)



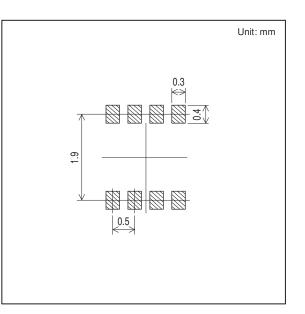


Those with pin 1 index on the feed hole side TL

Outline Drawing EMH2408-TL-H



Land Pattern Example



Note on usage : Since the EMH2408 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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